## **EAST Search History**

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	496581	semiconductor near3 (substrate or support or base or wafer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/09 15:52
L2	8334	epitaxial\$2 same crystalline	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/09 15:55
L3	23725	lattice-mismatch\$3 or (lattice near2 mismatch\$3) or (misfit near dislocation\$1) or (crystal\$4 near defect\$1)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/09 15:57
L4	240114	planariz\$3 or (smooth near2 surface)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/09 16:24
L5	319	I1 and I2 and I3 and I4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/09 17:00
L6	1144	I1 and I2 and I3 and (polish\$3 or etch\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/09 17:01